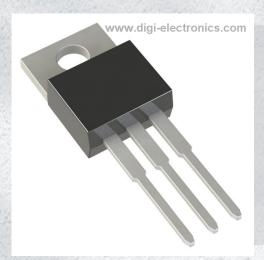


## **IXTP10N60P Datasheet**



https://www.DiGi-Electronics.com

DiGi Electronics Part Number IXTP10N60P-DG

Manufacturer IXYS

Manufacturer Product Number IXTP10N60P

Description MOSFET N-CH 600V 10A TO220AB

Detailed Description N-Channel 600 V 10A (Tc) 200W (Tc) Through Hole

TO-220-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXTP10N60P	IXYS
Series:	Product Status:
Polar	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
600 V	10A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	740mOhm @ 5A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5.5V @ 250µA	32 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	1610 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	200W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-220-3	TO-220-3
Base Product Number:	
IXTP10	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



## **OUR CERTIFICATE**

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